



# PerF±T<sup>™</sup>Power Transistor

#### **FEATURES**

- Excellent FOM
- Reliability meets AEC-Q101 requirements
- Wettable flank leads for enhanced AOI
- 100% UIS and Rg tested
- 175°C operating junction temperature
- RoHS Compliant
- Halogen-free

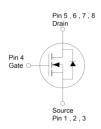
KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V <sub>D</sub>	V <sub>DS</sub>		V	
D (22.5.)	V <sub>GS</sub> = 10V	13		
R <sub>DS(on)</sub> (max)	$V_{GS} = 4.5V$	18.2	mΩ	
Qg	$V_{GS} = 4.5V$	8.4	nC	



#### **APPLICATIONS**

- Solenoid and motor drivers
- DC-DC converters
- Load Switch
- SMPS





Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	80	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	V	
	T <sub>C</sub> = 25°C	ID	54		
Continuous Drain Current	T <sub>C</sub> = 100°C		38	Α	
	$T_A = 25$ °C		10		
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	216	А	
Single Pulse Avalanche Current (Note 2)		I <sub>AS</sub>	12.7	А	
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	24.3	mJ	
Total Power Dissipation	Tc = 25°C	Б	82	W	
	T <sub>C</sub> = 125°C	$P_D$	27		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +175	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	Rejc	1.82	°C/W	
Junction to Ambient Thermal Resistance (Note 3)	R <sub>OJA</sub>	50	°C/W	

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#### Notes:

- 1. Pulse Width ≤ 100µs.
- 2. L = 0.3mH,  $V_{GS}$  = 10V,  $R_{G}$  = 25 $\Omega$ , Starting  $T_{J}$  = 25 $^{\circ}$ C.
- 3. Device on a PCB FR4 with 1 in² (single layer, 2 oz thickness) copper area for drain connection.



PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V$ , $I_D = 1mA$	BV <sub>DSS</sub>	80			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	V <sub>GS(TH)</sub>	1.4	1.9	2.2	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 80V	I <sub>DSS</sub>			1	μA
Drain-Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 80V T <sub>J</sub> = 125°C				100	
Drain-Source On-State Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 27A			10	13	mΩ
(Note 4)	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 27A	R <sub>DS(on)</sub>		14	18.2	
Forward Transconductance (Note 4)	$V_{DS} = 10V, I_D = 6.7A$	<b>g</b> fs		44		S
Dynamic (Note 5)		<u>.</u>				
Total Gate Charge	$V_{DS} = 40V, I_{D} = 10A,$ $V_{GS} = 4.5V$	Qg		8.4		nC
Total Gate Charge		Qg		17		
Gate-Source Charge	$V_{DS} = 40V, I_{D} = 10A,$ $V_{GS} = 10V$	Q <sub>gs</sub>		3.1		nC
Gate-Drain Charge		Q <sub>gd</sub>		3.2		
Input Capacitance		Ciss		975		
Output Capacitance	$V_{DS} = 40V, V_{GS} = 0V,$ f = 1.0MHz	Coss		565		pF
Reverse Transfer Capacitance	1 = 1.0IVIM2	Crss		28		
Gate Resistance	f = 1.0MHz	Rg		1.3		Ω
Switching (Note 6)						
Turn-On Delay Time		t <sub>d(on)</sub>	-	7.6		
Turn-On Rise Time	$V_{DD} = 40V, R_G = 6\Omega,$ $I_D = 10A, V_{GS} = 10V$	tr		24		
Turn-Off Delay Time		$t_{d(off)}$		20		ns
Turn-Off Fall Time		<b>t</b> f	-	25		
Source-Drain Diode						
Forward Voltage (Note 4)	I <sub>S</sub> = 27A, V <sub>GS</sub> = 0V	V <sub>SD</sub>			1.1	V
Reverse Recovery Time	Is = 10A,	t <sub>rr</sub>	-	45		ns
Reverse Recovery Charge	di/dt = 100A/μs	Qrr		49		nC

### Notes:

- 4. Pulse test: Pulse Width  $\leq$  300µs, duty cycle  $\leq$  2%.
- 5. Defined by design. Not subject to production test.
- 6. Switching time is essentially independent of operating temperature.

### **ORDERING INFORMATION**

ORDERING CODE	PACKAGE	PACKING
TSM130NH08LCR RLG	PDFN56U	2,500pcs / 13" Reel

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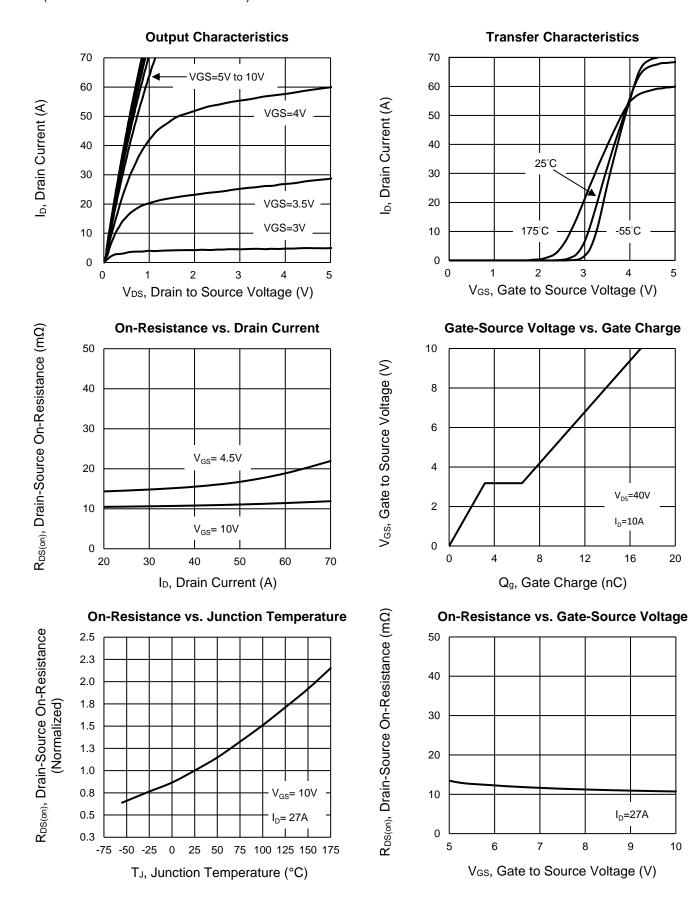
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### **CHARACTERISTICS CURVES**

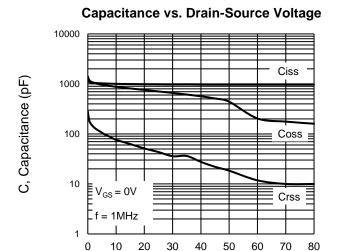
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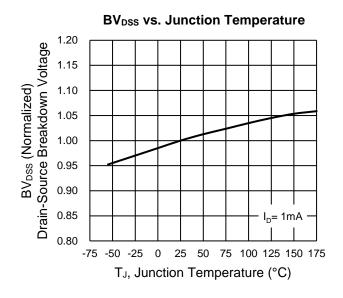




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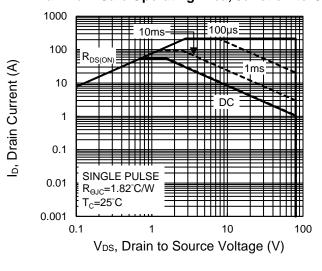
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 





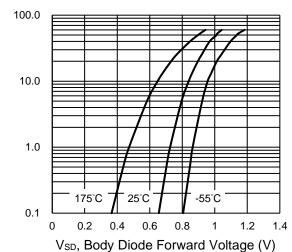
### Maximum Safe Operating Area, Junction-to-Case

V<sub>DS</sub>, Drain to Source Voltage (V)



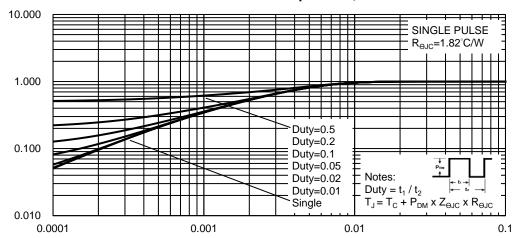
Normalized Effective Transient Thermal Impedance, Zeuc

### Source-Drain Diode Forward Current vs. Voltage



### Normalized Thermal Transient Impedance, Junction-to-Case

Is, Reverse Drain Current (A)



t, Square Wave Pulse Duration (sec)

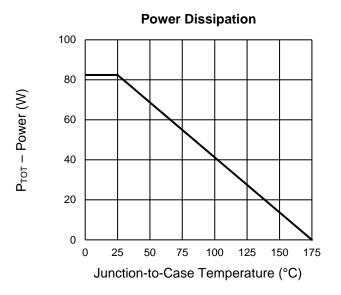
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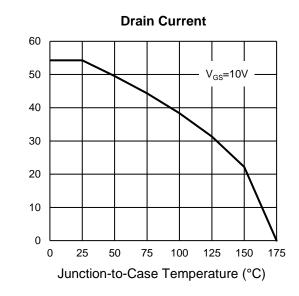


Taiwan Semiconductor

### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

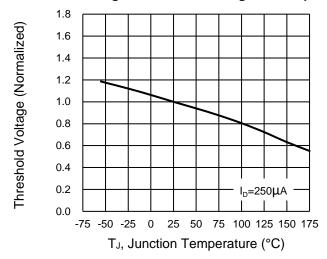




I<sub>D</sub>-Drain Current (A)

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### Normalized gate threshold voltage vs Temperature

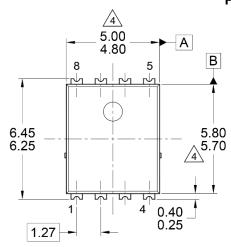


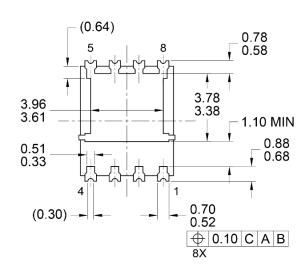


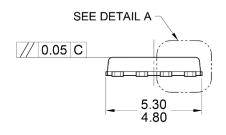
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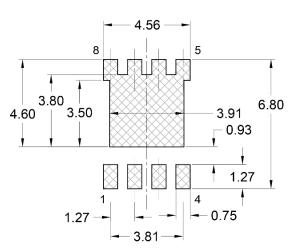
### PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

#### PDFN56U







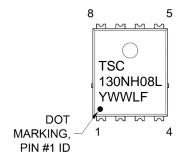


SUGGESTED PAD LAYOUT

(REFERENCE ONLY)

0.90MIN 1.10 0.90 0.30 0.20 PLATED AREA SEATING PLANE

DETAIL A (SCALE 2:1)



MARKING DIAGRAM

#### NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- PACKAGE OUTLINE REFERENCE: JEITA ED-7500B, EIAJ SC-111BB.
- MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 5. DWG NO. REF: HQ2SD07-PDFN56U-023 REV B.

130NH08L= Device marking

Y = Year code

WW = Week code  $(01\sim52)$ L = Lot code  $(1\sim9,A\sim Z)$ 

F = Factory code



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